Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	17	"4534314" and (insulat$4 or isolat$4)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/04/11 16:02
L2	6711	(250/492.21,492.3,492.2,440.11, 398).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/04/11 16:03
L3	1552	(current near4 integrat$4) and (ion near implant$7)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/04/11 16:14
L4	11	l3 and (wafer near4 cassette)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/04/11 16:07
L5	11	l3 and ((wafer near4 cassette) or wafer-cassette)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/04/11 16:05
L6	19	l3 and (wafer and cassette)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/04/11 16:07
L7	8	l6 not l5	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/04/11 16:08
L8	368	(current near integrat$4) and (ion near implant$7)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/04/11 16:15

L9	339	I8 and (wafer or substrate)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/04/11 16:15
L10	15	I9 and cassette	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/04/11 16:28
L11	11	I10 and insulat$5	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/04/11 16:28
L12	1	"I18" and I2	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/04/11 16:56
L13	54	I8 and I2	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/04/11 16:27
L14	47	I3 and cassette	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/04/11 16:28
L15	18	I14 and insulat$5	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/04/11 16:28
L16	162	ion and implant$7 and slot and I2	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/04/11 16:57

L17	19	I16 and current and cassette	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/04/11 17:17
L18	38	cassette and ion and (current near1 integrat$5)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/04/11 17:18
L19	10	I18 and (slot or groov$3)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/04/11 17:22
L20	28	I18 not I19	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/04/11 17:26
L21	636	(ion near implant$7) and current and insulat$4 and cassette	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/04/11 17:26
L22	9	I21 and pillar	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/04/11 17:37
L23	1	(ion adj implant$8) and (current near integrat$5) and cassette and (slot or groove) and insulat$6	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/04/11 17:38